

- Ideal for 319 MHz Transmitters
- Very Low Series Resistance
- Quartz Stability
- Surface-Mount, Ceramic Case with 21 mm² Footprint
- Complies with Directive 2002/95/EC (RoHS)

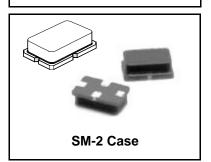
The RO2135A is a one-port, surface-acoustic-wave (SAW) resonator in a surface-mount ceramic case. It provides reliable, fundamental-mode, quartz frequency stabilization of fixed-frequency transmitters operating at 319 MHz. Applications include remote-control and wireless security receivers operating in the USA under FCC Part 15 and in Canada under DoC RSS-210.

Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation	+10	dBm
DC Voltage Between Terminals (Observe ESD Precautions)	±30	VDC
Case Temperature ¹	-40 to +85	°C
Soldering Temperature	+250	°C

RO2135A

319.508 MHz SAW Resonator



Electrical Characteristics

Cha	aracteristic	Sym	Notes	Minimum	Typical	Maximum	Units
Center Frequency at +25 °C	Absolute Frequency	f _C	2, 3, 4, 5		319.508		MHz
	Tolerance from 319.508 MHz	Δf_{C}	2, 3, 4, 3			±75	kHz
Insertion Loss	Insertion Loss		2, 5, 6		1.1	2.2	dB
Quality Factor	Unloaded Q	Q _U	567		19,200		
	$SO_{\rm L}$ Source $SO_{\rm L}$		1,500				
Temperature Stability	Turnover Temperature	T _O	0	10	25	40	°C
	Turnover Frequency	f _O	6, 7, 8		f _C		
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C ²
Frequency Aging	Absolute Value during the First Year	fA	1		≤10		ppm/yr
DC Insulation Resistance between Any Two Terminals			5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R_{M}	5, 7, 9	8.768	8.4	9.27	Ω
	Motional Inductance	L _M			80.9629		μH
	Motional Capacitance	C _M			3.06		fF
	Transducer Static Capacitance	Co	5, 6, 9	3.4	3.5	3.56	pF
Test Fixture Shunt Inductance		L _{TEST}	2, 7		69.85		nH
Lid Symbolization (in Addition to to Lot and/or Date Code)		176					

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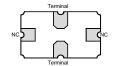
CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. Notes:

- 1. Lifetime (10 year) frequency aging.
- 2. The center frequency, f_C , is measured at the minimum insertion loss point, IL_{MIN} , with the resonator in the 50 Ω test system (VSWR \leq 1.2:1). The shunt inductance, L_{TEST} , is tuned for parallel resonance with C_O at f_C .
- One or more of the following United States patents apply: 4,454,488 and 4,616,197.
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 5. Unless noted otherwise, case temperature $T_C = +25^{\circ}C \pm 2^{\circ}C$.
- The design, manufacturing process, and specifications of this device are subiect to change without notice.
- Derived mathematically from one or more of the following directly measured parameters: f_C, IL, 3 dB bandwidth, f_C versus T_C, and C_O.
- Turnover temperature, T_O, is the temperature of maximum (or turnover) frequency, f_O. The nominal frequency at any case temperature, T_C, may be calculated from: f = f_O [1 FTC (T_O -T_C)²].
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_O is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can by calculated as: C_P ≈ C_O 0.05 pF.

SAW Resonator

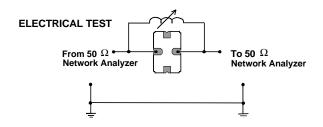
Electrical Connections

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit

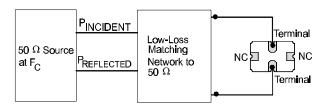


Typical Test Circuit

The test circuit inductor, L_{TEST} , is tuned to resonate with the static capacitance, C_{O} , at F_{C} .

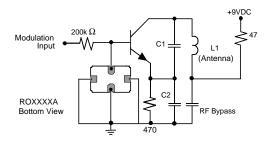


POWER TEST

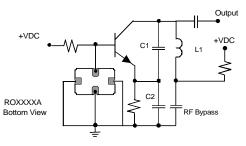


CW RF Power Dissipation = P_{INCIDENT} - P_{REFLECTED} **Typical Application Circuits**

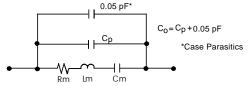
Typical Low-Power Transmitter Application



Typical Local Oscillator Application

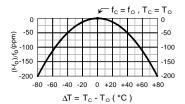


Equivalent LC Model



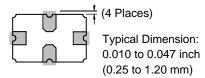
Temperature Characteristics

The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.



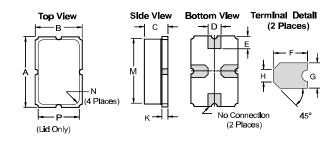
Typical Circuit Board Land Pattern

The circuit board land pattern shown below is one possible design. The optimum land pattern is dependent on the circuit board assembly process which varies by manufacturer. The distance between adjacent land edges should be at a maximum to minimize parasitic capacitance. Trace lengths from terminal lands to other components should be short and wide to minimize parasitic series inductances.



Case Design

The case material is black alumina with contrasting symbolization. All pads are nominally centered with respect to the base and consist of 40 to 70 microinches electroless gold on 60-350 microinches electroless nickel.



Dimensions	Millim	neters	Inches		
	Min	Max	Min	Max	
A	5.74	5.99	0.226	0.236	
В	3.73	3.99	0.147	0.157	
С	1.91	2.16	0.075	0.085	
D	0.94	1.10	0.037	0.043	
Е	0.83	1.20	0.033	0.047	
F	1.16	1.53	0.046	0.060	
G	0.94	1.10	0.037	0.043	
Н	0.43	0.59	0.017	0.023	
K	0.43	0.59	0.017	0.023	
М	5.08	5.33	0.200	0.210	
N	0.38	0.64	0.015	0.025	
Р	3.05	3.30	0.120	0.130	